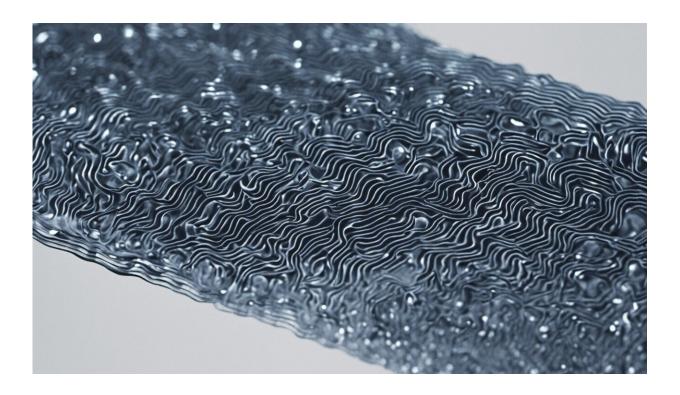


## Silicon-carbide modulator overcomes decades long 'missing block'

April 14 2022



Credit: AI-generated image (disclaimer)

A collaboration with Harvard University has led to the development of a new-generation electro-optic modulator that could stamp out its bulky predecessor through the creation of a smaller, stronger, cooler, faster and cost-effective on-chip system.



The new modulator was made possible through the harnessing of a "difficult" compound—<u>silicon carbide</u>. Silicon carbide was first recognized as a photonics wonder material more than three decades ago when it was found to display the "Pockels effect"—a light polarizing technique used in <u>electrical engineering</u>. Despite silicon carbide's exceptional durability in demanding electrical, mechanical and radiation environments, its use in photonics has been limited.

The researchers believe their technique, which was described in *Nature Communications*, will advance quantum communications and microwave photonics by facilitating photonic integration; the co-integration with traditional electronics and quantum emitters.

Lead researcher from the University of Sydney's School of Electrical and Information Engineering Professor Xiaoke Yi said: "The use of silicon carbide will potentially open up a new chapter of opportunities in photonics for various applications including <u>quantum computing</u>."

Electro-optic modulators encode <u>electrical signals</u> onto an optical carrier. They are essential for the operation of global communication systems and data centers used in a range of applications and industry settings such as <u>artificial intelligence</u> (AI), broadband networks, and highperformance computing.

"Modulators that use the Pockels effect enable low loss, ultrafast and wide-bandwidth data transmission. Overcoming the previous unworkability of silicon carbide may allow for unique photonicintegrated circuits to transmit and process wideband and fast-speed signals—as well as for emerging quantum technologies," said Professor Yi, who is an affiliate of the Sydney Nano Institute.

"We also hope that it will help integrate photonics with electronics—potentially paving the way for a new generation of



integrated devices used for <u>signal processing</u>, microwave photonics, chipto-chip, or intra-chip interconnects."

Lead researcher from Harvard University, Professor Marko Loncar said: "The silicon carbide modulator will likely find applications in <u>quantum</u> <u>communications</u>. For example, they could be used to control temporal and spectral properties of quantum emitters that exist in this material, as well as to route the photons in reconfigurable fashion."

The University of Sydney and Harvard modulator was shown to have no signal degradation, and demonstrated stable operations at high optical intensities, allowing for high optical signal-to-noise ratios for modern communications in datacenters, 6G and satellites, and future quantum internet.

**More information:** Keith Powell et al, Integrated silicon carbide electro-optic modulator, *Nature Communications* (2022). <u>DOI:</u> 10.1038/s41467-022-29448-5

Provided by University of Sydney

Citation: Silicon-carbide modulator overcomes decades long 'missing block' (2022, April 14) retrieved 25 April 2024 from <u>https://phys.org/news/2022-04-silicon-carbide-modulator-decades-block.html</u>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.